

V _{DSS}	650V
R _{DS(on)} (Typ.)	$17 \mathrm{m}\Omega$
I _D	118A
P _D	427W

Features

- 1) Low on-resistance
- 2) Fast switching speed
- 3) Fast reverse recovery
- 4) Easy to parallel
- 5) Simple to drive
- 6) Pb-free lead plating ; RoHS compliant

Application

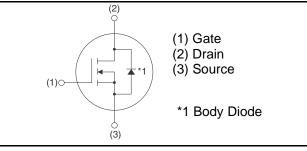
- Solar inverters
- DC/DC converters
- Switch mode power supplies
- Induction heating
- Motor drives

• Absolute maximum ratings $(T_a = 25^{\circ}C)$

•Outline



Inner circuit



Packaging specifications

	Packing	Tube
	Reel size (mm)	-
Tuno	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	30
	Taping code	C11
	Marking	SCT3017AL

Parameter	Symbol	Value	Unit	
Drain - Source voltage	V _{DSS}	650	V	
Continuous drain current	$T_c = 25^{\circ}C$	۱ _D *1	118	А
	$T_c = 100^{\circ}C$	۱ _D *1	83	А
Pulsed drain current	I _{D,pulse} *2	295	А	
Gate - Source voltage	V _{GSS}	-4 to 22	V	
Gate-Source Surge Voltage	V _{GSS_surge}	-4 to 22	V	
Recommended Drive Voltage	V _{GS_op}	0 / 18	V	
Junction temperature	Tj	175	°C	
Range of storage temperature	T _{stg}	-55 to +175	°C	

•Thermal resistance

Parameter	Symbol	Values			Unit
	Symbol	Min.	Тур.	Max.	Onit
Thermal resistance, junction - case	R _{thJC}	-	0.27	0.35	°C/W

•Electrical characteristics ($T_a = 25^{\circ}C$)

Parameter	Symbol	Conditions	Values			Unit	
Farameter	Symbol Conditions -		Min.	Тур.	Max.	Onit	
Drain - Source breakdown voltage	V _{(BR)DSS}	$V_{GS} = 0V, I_D = 1mA$	650	-	-	V	
		$V_{DS} = 650V, V_{GS} = 0V$					
Zero gate voltage drain current	I _{DSS}	T _j = 25°C	-	1	10	μA	
		T _j = 150°C	-	2	-		
Gate - Source leakage current	I_{GSS^+}	$V_{GS} = +22V, V_{DS} = 0V$	-	-	100	nA	
Gate - Source leakage current	I _{GSS-}	$V_{GS} = -4V, V_{DS} = 0V$	-	-	-100	nA	
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = 10V, I_{D} = 23.5mA$	2.7	-	5.6	V	
		$V_{GS} = 18V, I_{D} = 47A$					
Static drain - source on - state resistance	${\sf R}_{\sf DS(on)}$ *3	$T_j = 25^{\circ}C$	-	17	22.1	mΩ	
		T _j = 125°C	-	22.4	-		
Gate input resistance	R _G	f = 1MHz, open drain	-	4	-	Ω	

•Example of acceptable Vgs waveform



•Electrical characteristics ($T_a = 25^{\circ}C$)

Doromotor	Symbol	Conditions	Values			الم:4	
Parameter	Symbol Conditions -		Min.	Тур.	Max.	Unit	
Transconductance	g_{fs} *3	$V_{DS} = 10V, I_{D} = 47A$	-	16	-	S	
Input capacitance	C _{iss}	$V_{GS} = 0V$	-	2884	-		
Output capacitance	C _{oss}	V _{DS} = 500V	-	148	-	pF	
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	65	-		
Effective output capacitance, energy related	C _{o(er)}	$V_{GS} = 0V$ $V_{DS} = 0V$ to 300V	-	397	-	pF	
Turn - on delay time	t _{d(on)} *3	$V_{DD} = 300V, I_{D} = 18A$	-	30	-		
Rise time	t _r *3	V _{GS} = 18V/0V	-	44	-	20	
Turn - off delay time	t _{d(off)} *3	$R_L = 17\Omega$	-	64	-	ns	
Fall time	t _f *3	$R_{G} = 0\Omega$	-	31	-		
Turn - on switching loss	E _{on} *3	$V_{DD} = 300V, I_{D} = 47A$ $V_{GS} = 18V/0V$	-	369	-		
Turn - off switching loss	E _{off} *3	$R_G = 0\Omega L=250\mu H$ *E _{on} includes diode reverse recovery	-	156	-	μJ	

•Gate Charge characteristics ($T_a = 25^{\circ}C$)

Parameter	Symbol	Conditions	Values			Unit
Faranieler	Symbol Conditions -		Min.	Тур.	Max.	Offic
Total gate charge	Q_g^{*3}	V _{DD} = 300V	-	172	-	
Gate - Source charge Q _{gs} *3		I _D = 47A	-	40	-	nC
Gate - Drain charge	Q_{gd} *3	V _{GS} = 18V	-	70	-	
Gate plateau voltage	V _(plateau)	$V_{DD} = 300V, I_{D} = 47A$	-	9.6	-	V

*1 Limited only by maximum temperature allowed.

*2 PW \leq 10 $\mu s,$ Duty cycle \leq 1%

*3 Pulsed

●Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

Deremeter	Symbol	Conditions	Values			Unit	
Parameter Symbol		Conditions	Min.	Тур.	Max.	Unit	
Inverse diode continuous, forward current	ا _S *1	T _c = 25°C	-	-	118	А	
Inverse diode direct current, pulsed	I _{SM} *2	T _c = 25 C	-	-	295	A	
Forward voltage	V_{SD} *3	$V_{GS} = 0V, I_{S} = 47A$	-	3.2	-	V	
Reverse recovery time	t _{rr} *3		-	31	-	ns	
Reverse recovery charge	() °	I _F = 47A, V _R = 300V di/dt = 1100A/μs	-	206	-	nC	
Peak reverse recovery current	I _{rrm} ^{*3}		-	13	-	А	

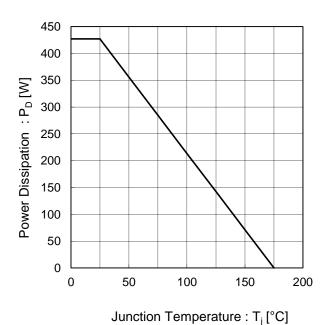


Fig.1 Power Dissipation Derating Curve

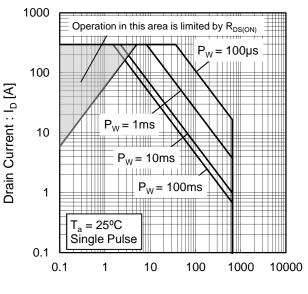


Fig.2 Maximum Safe Operating Area

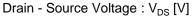


Fig.3 Typical Transient Thermal Resistance vs. Pulse Width

Fig.5 Typical Output Characteristics(II)

•Electrical characteristic curves

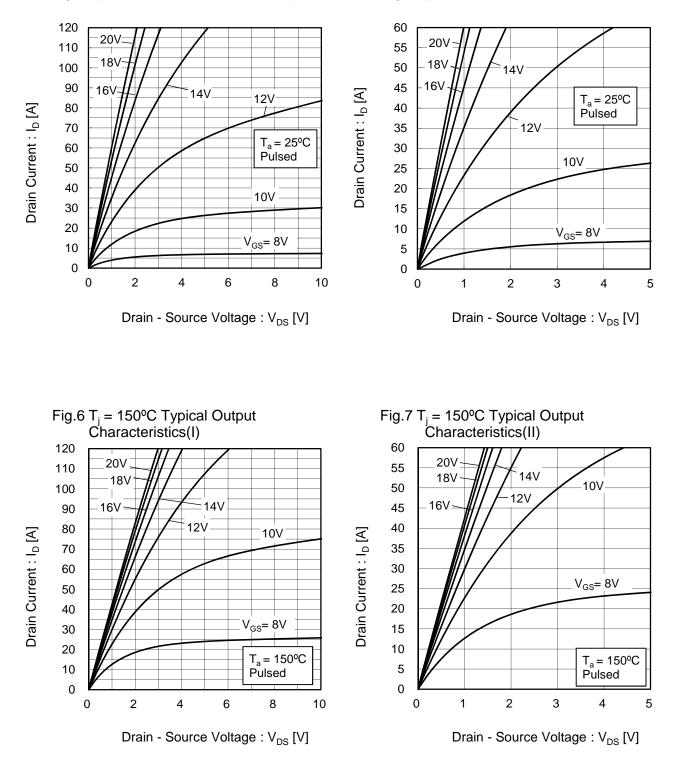


Fig.4 Typical Output Characteristics(I)

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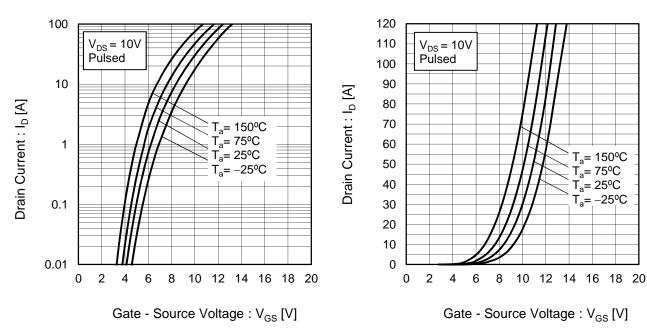
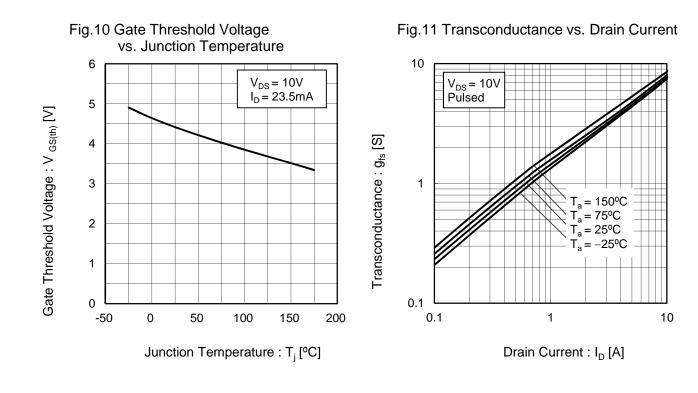
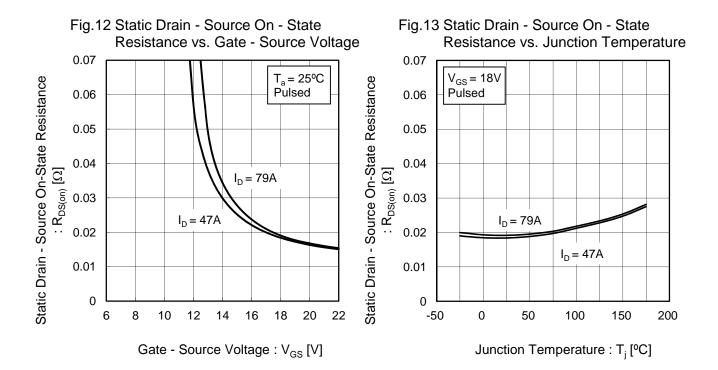
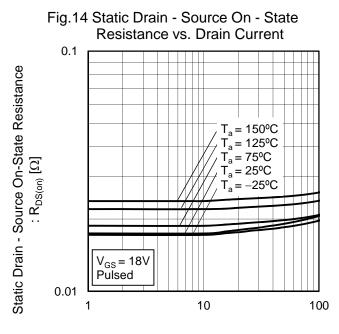


Fig.8 Typical Transfer Characteristics (I)

Fig.9 Typical Transfer Characteristics (II)







Drain Current : I_D [A]

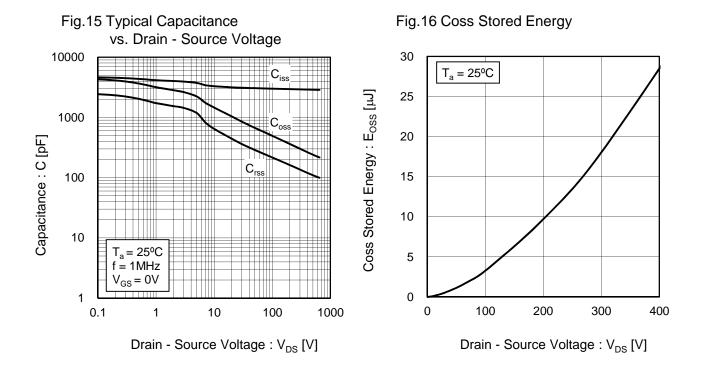


Fig.17 Switching Characteristics

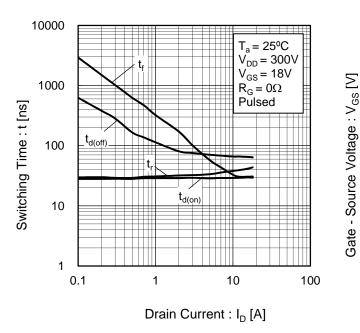
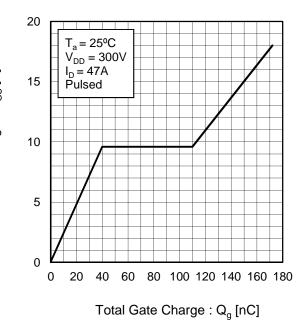
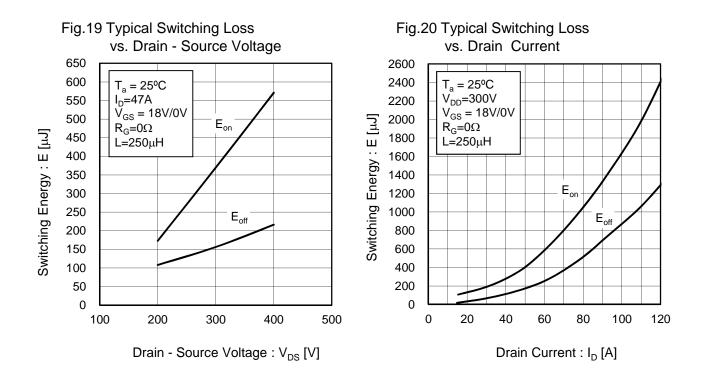


Fig.18 Dynamic Input Characteristics





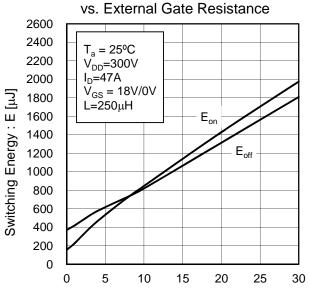
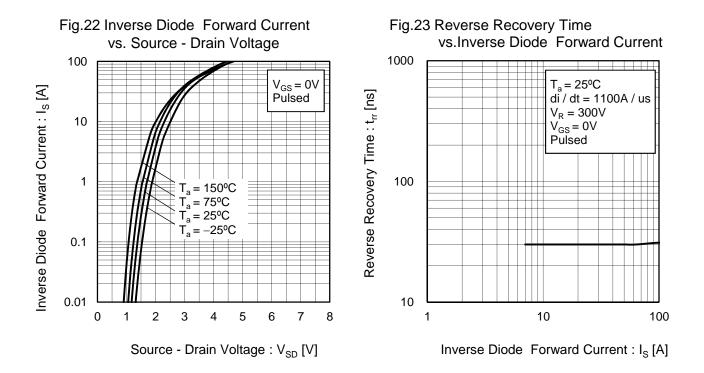


Fig.21 Typical Switching Loss

External Gate Resistance : $\mathsf{R}_{\mathsf{G}}\left[\Omega\right]$





Measurement circuits



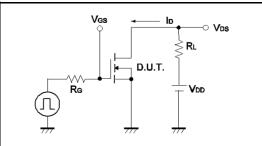


Fig.2-1 Gate Charge Measurement Circuit

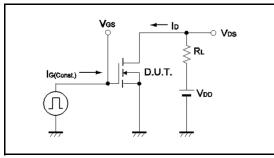


Fig.3-1 Switching Energy Measurement Circuit

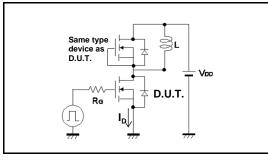
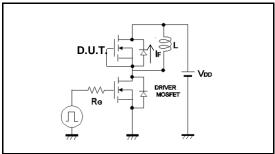
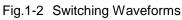


Fig.4-1 Reverse Recovery Time Measurement Circuit Fig.4-2 Reverse Recovery Waveform





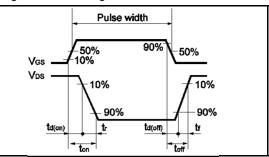


Fig.2-2 Gate Charge Waveform

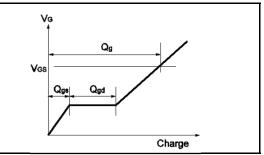
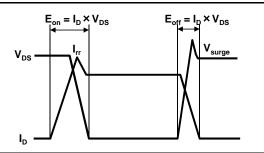
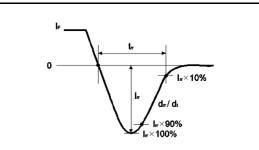


Fig.3-2 Switching Waveforms







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Distribution Inventory

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Unit Quantity	450
Minimum Package Quantity	30
Packing Type	Tube
Constitution Materials List	inquiry
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